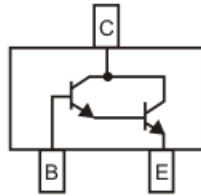
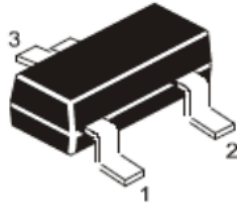


NPN SURFACE MOUNT DARLINGTON TRANSISTOR



CMBTA28
SOT-23
Surface Mounted
Plastic Package

MARKING CODE: A28

FEATURES

- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- High Current Gain

MAXIMUM RATINGS @ $T_A = 25^\circ\text{C}$ unless otherwise specified

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	V_{CES}	80	V
Emitter-Base Voltage	V_{EBO}	12	V
Collector Current – Continuous	I_C	500	mA
Power Dissipation	P_d	300	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Operating and Storage and Temperature Range	T_j, T_{STG}	-55 to 150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$ unless otherwise specified

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNIT
OFF CHARACTERISTICS (Note 1)					
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=100\mu\text{A}, I_E=0$	80		V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=100\mu\text{A}, I_C=0$	12		V
Collector-Emitter Voltage	V_{CES}	$I_C=100\mu\text{A}, V_{BE}=0$	80		V
Collector Cutoff Current	I_{CBO}	$V_{CB}=60\text{V}, I_E=0$		100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=10\text{V}, I_C=0$		100	nA
ON CHARACTERISTICS (Note 1)					
DC Current Gain	h_{FE}	$I_C=10\text{mA}, V_{CE}=5.0\text{V}$	10,000		
		$I_C=100\text{mA}, V_{CE}=5.0\text{V}$	10,000		
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=100\text{mA}, I_B=100\mu\text{A}$		1.5	V
Base- Emitter On Voltage	$V_{BE(on)}$	$I_C=100\text{mA}, V_{CE}=5.0\text{V}$		2.0	V
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C_{obo}	$V_{CB}=10\text{V}, f=1.0\text{MHz}, I_E=0$	8.0 Typical		pF
Input Capacitance	C_{ibo}	$V_{EB}=0.5\text{V}, f=1.0\text{MHz}, I_C=0$	15 Typical		pF
Current Gain-Bandwidth Product	f_T	$V_{CE}=5.0\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	125		MHz

Notes:

1. Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$



Continental Device India Pvt. Limited
An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



Customer Notes:

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

DISCLAIMER

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).



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